NSN 5961-00-828-8575

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View Online at https://aerobasegroup.com/nsn/5961-00-828-8575 **Inclosure Material:** Metal **Overall Length:** 0.460 inches **Overall Diameter:** 0.610 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open and 45.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 20.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 3.5 watts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release3333 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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